NSN 5961-00-104-8583

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-104-8583 **Inclosure Material:** Glass and metal **Overall Length:** 0.437 inches **Overall Diameter:** 0.160 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.5 regulator voltage **Current Rating Per Characteristic:** 20.00 milliamperes average forward current averaged over a full 60-hz cycle **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No